

# **PMPB50ENEX Datasheet**

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DiGi Electronics Part Number PMPB50ENEX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PMPB50ENEX

Description MOSFET DFN2020MD-6

**Detailed Description** N-Channel 30 V 6.9A (Ta) 1.9W (Ta) Surface Mount

DFN2020MD-6



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
PMPB50ENEX	Nexperia USA Inc.
Series:	Product Status:
	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
30 V	6.9A (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
4.5V, 10V	43mOhm @ 5.1A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
2.5V @ 250μA	10 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	271 pF @ 15 V
FET Feature:	Power Dissipation (Max):
	1.9W (Ta)
Operating Temperature:	Mounting Type:
-55°C ~ 175°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
DFN2020MD-6	6-UDFN Exposed Pad
Base Product Number:	
PMPB50	

# **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

**Product data sheet** 

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Extended temperature range T<sub>i</sub> = 175 °C
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Tin-plated 100 % solderable side pads for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- Trench MOSFET technology

### 3. Applications

- · Relay driver
- · High-speed line driver
- Low-side load switch
- · Switching circuits

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	6.9	Α
Static characte	ristics						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 5.1 \text{ A}; T_j = 25 \text{ °C}$		-	30	43	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		
4	S	source	2 5	G ( T)
5	D	drain	3 8 4	\ <del>\\</del>
6	D	drain	Transparent top view	
7	D	drain	DFN2020MD-6 (SOT1220)	S 017aaa255
8	S	source		0174da255

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
PMPB50ENE		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMPB50ENE	3U

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
$V_{GS}$	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	6.9	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	5.1	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	3.2	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	20	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[1]	-	1.9	W
		T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	3.8	W
		T <sub>sp</sub> = 25 °C		-	11	W
T <sub>j</sub>	junction temperature			-55	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C
Source-drain	diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	2	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

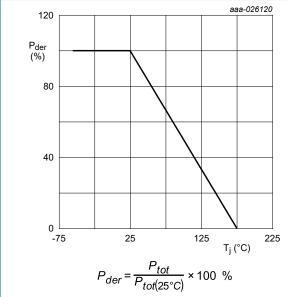


Fig. 1. Normalized total power dissipation as a function of junction temperature

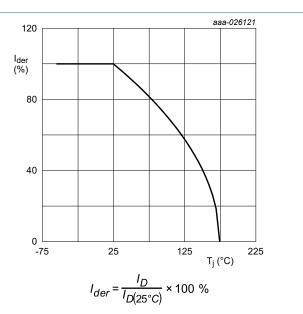


Fig. 2. Normalized continuous drain current as a function of junction temperature

#### 30 V, N-channel Trench MOSFET

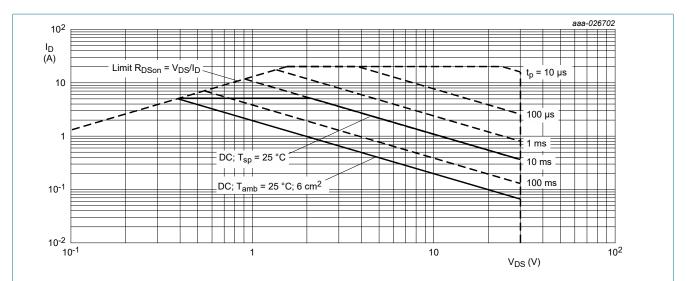


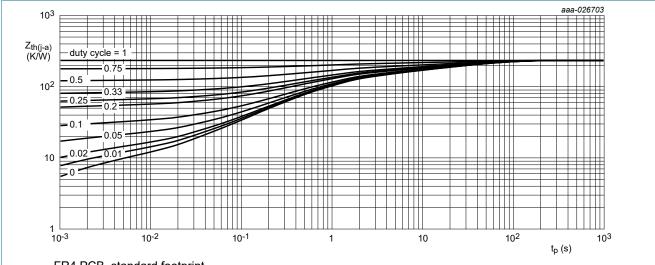
Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

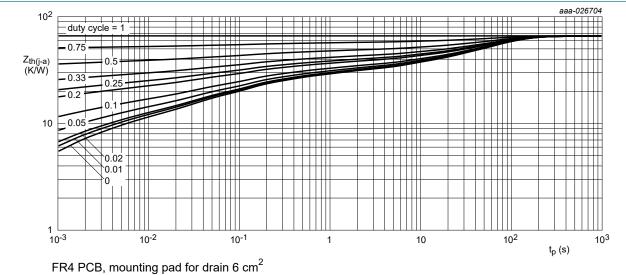
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient	in free air [1	[1]	-	238	274	K/W	
		[2]	-	67	77	K/W	
		in free air; t ≤ 5 s	[2]	-	35	40	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	11	14	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 4.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

# 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1	1.5	2.5	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-10	μA
		$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	200	nA
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-200	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = 10 \text{ V}; I_D = 5.1 \text{ A}; T_j = 25 \text{ °C}$	-	30	43	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.1 A; T <sub>j</sub> = 175 °C	-	54	78	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 4.2 \text{ A}; T_j = 25 \text{ °C}$	-	39	60	mΩ
9fs	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 5.1 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	13	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	6.6	-	Ω
Dynamic ch	naracteristics		'			'
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 5.1 A; V <sub>GS</sub> = 10 V;	-	6	10	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.7	-	nC
Q <sub>GD</sub>	gate-drain charge		-	1.3	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	271	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	58	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	43	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 5.1 A; V <sub>GS</sub> = 10 V;	-	4	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	24	-	ns
t <sub>d(off)</sub>	turn-off delay time	]	-	17	-	ns
t <sub>f</sub>	fall time	]	-	6	-	ns
Source-dra	in diode		'		,	,
V <sub>SD</sub>	source-drain voltage	$I_S = 2 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	0.8	1.2	V

#### 30 V, N-channel Trench MOSFET

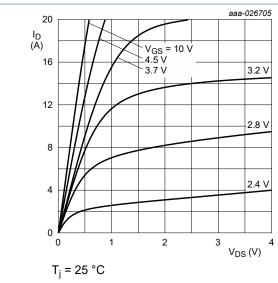


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

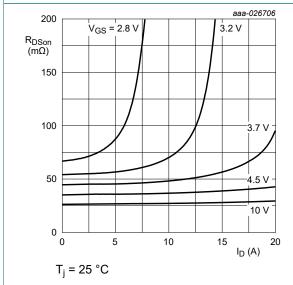


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

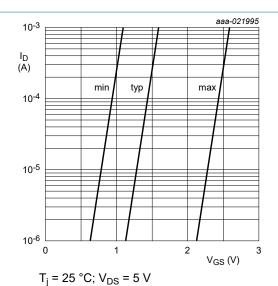


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

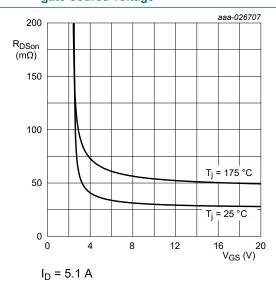


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

#### 30 V, N-channel Trench MOSFET

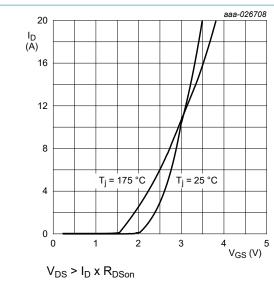


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

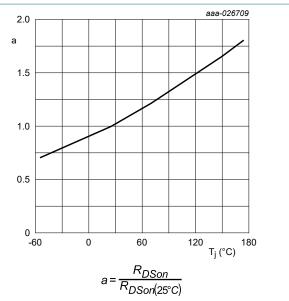


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

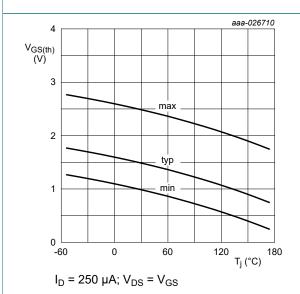


Fig. 12. Gate-source threshold voltage as a function of junction temperature

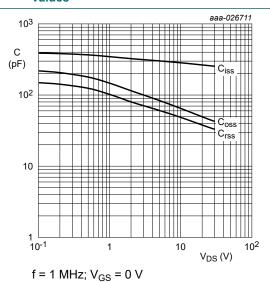


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

#### 30 V, N-channel Trench MOSFET

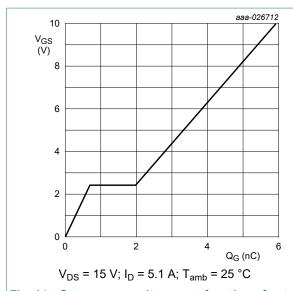


Fig. 14. Gate-source voltage as a function of gate charge; typical values

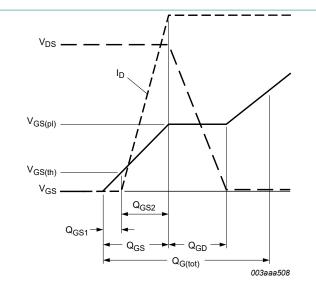


Fig. 15. Gate charge waveform definitions

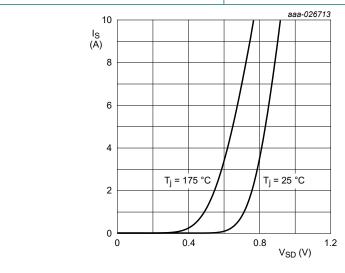
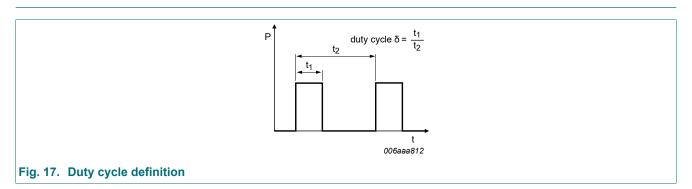


Fig. 16. Source current as a function of source-drain voltage; typical values

### 11. Test information

 $V_{GS} = 0 V$ 



30 V, N-channel Trench MOSFET

# 12. Package outline

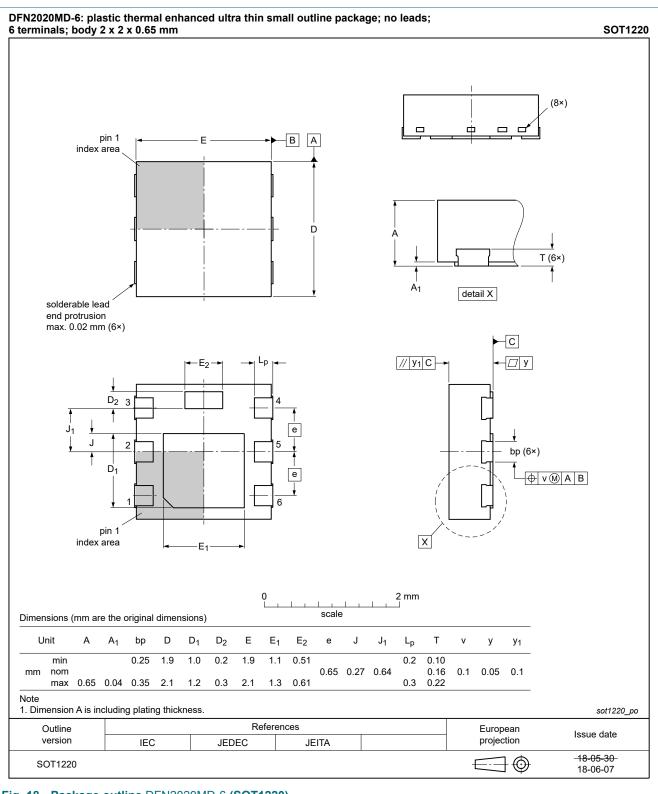
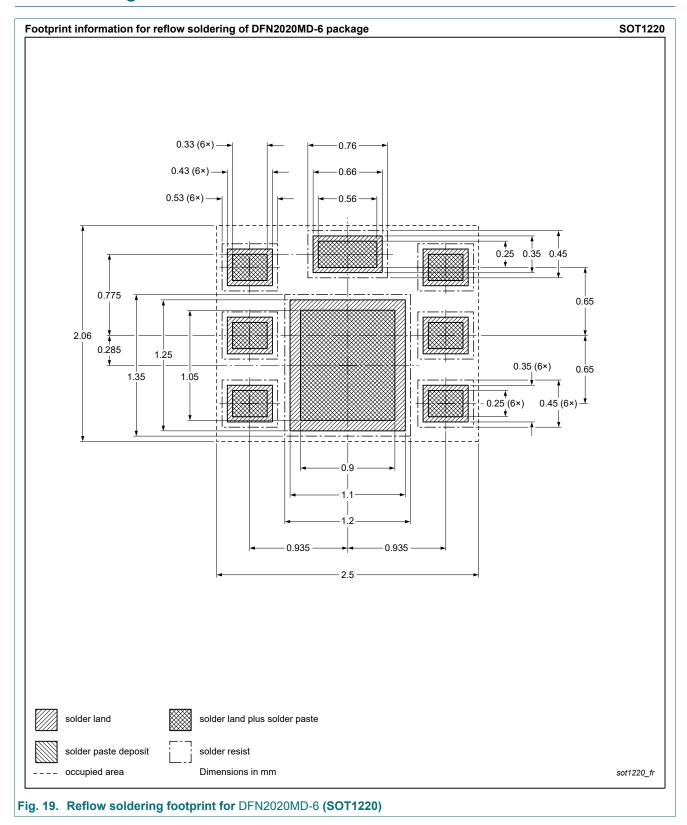


Fig. 18. Package outline DFN2020MD-6 (SOT1220)

30 V, N-channel Trench MOSFET

# 13. Soldering



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# 14. Revision history

#### Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PMPB50ENE v.2	20220120	Product data sheet	-	PMPB50ENE v.1				
Modifications:	Chapter "Limiting values": typo correction, unit for P <sub>tot</sub> changed							
PMPB50ENE v.1	20180426	Product data sheet	-	-				

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### Nexperia

### **PMPB50ENE**

#### 30 V, N-channel Trench MOSFET

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